

High-Speed Drivers with Dual SPDT JFET Switches

FEATURES

- Constant On-Resistance Over Entire Analog Range
- Low Leakage
- Low Crosstalk
- Low Crosstalk
- Rad Hardness

BENEFITS

- Low Distortion
- Eliminates Large Signal Errors
- High Precision
- High Bandwidth Capability
- Fault Protection

APPLICATIONS

- Audio Switching
- Video Switching
- Sample/Hold
- Guidance and Control Systems
- Aerospace

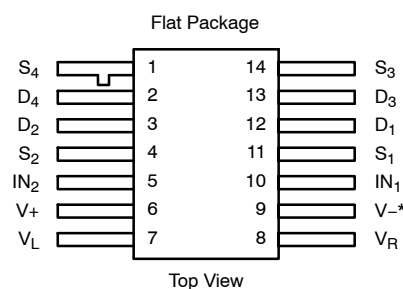
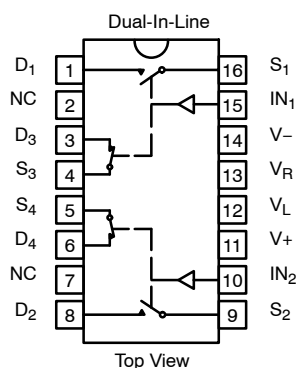
DESCRIPTION

The DG189/190/191 are precision dual single-pole, double-throw (SPDT) analog switches designed to provide accurate switching of video and audio signals. This series is ideally suited for applications requiring a constant on-resistance over the entire analog range.

The major difference in the devices is the on-resistance (DG189—10 Ω , DG190—30 Ω , DG191—75 Ω). Reduced errors are achieved through low leakage current ($I_{D(on)} < 2$ nA). Applications which benefit from the flat JFET on-resistance include audio switching, video switching, and data acquisition.

To achieve fast and accurate switch performance, each device comprises four n-channel JFET transistors and a TTL compatible bipolar driver. The driver is designed to achieve break-before-make switching action, eliminating the inadvertent shorting between channels and the crosstalk which would result. In the on state, each switch conducts current equally well in either direction. In the off condition, the switches will block up to 20 V peak-to-peak, with feedthrough of less than -60 dB at 10 MHz.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Refer to JAN38510 Information, Military Section

*Common to Substrate and Case

TRUTH TABLE		
Logic	SW ₁ , SW ₂	SW ₃ , SW ₄
0	OFF	ON
1	ON	OFF

Logic "0" ≤ 0.8 V
Logic "1" ≥ 2.4 V



ORDERING INFORMATION		
Temp Range	Package	Part Number
-25 to 85°C	16-Pin Sidebrazed	DG189BP
		DG190BP
		DG191BP
-55 to 125°C	16-Pin Sidebrazed	DG189AP
		DG190AP
		DG191AP
		DG189AP, DG189AP/883, 5962-9068901MEA
		DG190AP, DG190AP/883, JM38510/11107BEA
		DG191AP, DG191AP/883, JM38510/11108BEA
	14-Pin Flat Pack	JM38510/11107BXA
		JM38510/11108BXA

ABSOLUTE MAXIMUM RATINGS

V_+ to V_-	36 V	Current (S or D) DG190, DG191	30 mA
V_+ to V_D	33 V	Current (All Other Pins)	30 mA
V_S, V_D to V_-	-0.3 to 33 V	Storage Temperature	-65 to 150°C
V_D to V_D	± 22 V	Power Dissipation ^a	
V_L to V_-	36 V	16-Pin Sidebrazed ^b	900 mW
V_L to V_{IN}	8 V	14-Pin Flat Pack ^c	900 mW
V_L to V_R	8 V		
V_{IN} to V_R	8 V	Notes:	
V_R to V_-	27 V	a. All leads welded or soldered to PC Board.	
V_R to V_{IN}	2 V	b. Derate 12 mW/°C above 75°C	
Current (S or D) DG189	200 mA	c. Derate 10 mW/°C above 75°C	

SCHEMATIC DIAGRAM (TYPICAL CHANNEL)

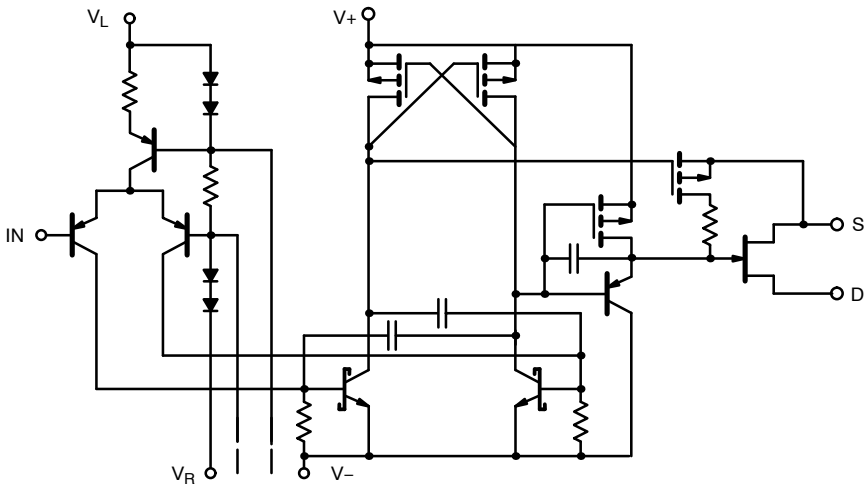


FIGURE 1.

**SPECIFICATIONS^a FOR DG189**

Parameter	Symbol	Test Conditions Unless Specified V ₊ = 15 V, V ₋ = -15 V, V _L = 5 V V _R = 0 V, V _{IN} = 0.8 V or 2 V ^f	Temp ^b	Typ ^c	A Suffix -55 to 125°C		B Suffix -25 to 85°C		Unit	
					Min ^d	Max ^d	Min ^d	Max ^d		
Analog Switch										
Analog Signal Range ^e	V _{ANALOG}		Full		-7.5	15	-7.5	15	V	
Drain-Source On-Resistance	r _{DS(on)}	I _S = -10 mA, V _D = -7.5 V	Room Full	7.5		10 20		15 25	Ω	
Source Off Leakage Current	I _{S(off)}	V _S = ±10 V, V _D = ∓10 V V ₊ = 10 V, V ₋ = -20 V	Room Hot	0.05		10 1000		15 300	nA	
		V _S = ±7.5 V, V _D = ∓7.5 V	Room Hot	0.05		10 1000		15 300		
Drain Off Leakage Current	I _{D(off)}	V _S = ±10 V, V _D = ∓10 V V ₊ = 10 V, V ₋ = -20 V	Room Hot	0.04		10 1000		15 300		
		V _S = ±7.5 V, V _D = ∓7.5 V	Room Hot	0.03		10 1000		15 300		
Channel On Leakage Current	I _{D(on)}	V _D = V _S = ±7.5 V	Room Hot	-0.1	-2 -200		-10 -200			
Saturation Drain Current	I _{DSS}	2 ms Pulse Duration	Room	300					mA	
Digital Input										
Input Current with Input Voltage High	I _{INH}	V _{IN} = 5 V	Room Hot	<0.01		10 20		10 20	μA	
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0 V	Full	-30	-250		-250			
Dynamic Characteristics										
Turn-On Time	t _{on}	See Switching Time Test Circuit		Room	240		400		425	ns
Turn-Off Time	t _{off}			Room	140		200		225	
Source-Off Capacitance	C _{S(off)}	f = 1 MHz	V _S = -5 V, I _D = 0	Room	21					pF
Drain-Off Capacitance	C _{D(off)}		V _D = -5 V, I _S = 0	Room	17					
Channel-On Capacitance	C _{D(on)}		V _D = V _S = 0 V	Room	17					
Off Isolation	OIRR	f = 1 MHz, R _L = 75 Ω		Room	>55					dB
Power Supplies										
Positive Supply Current	I ₊	V _{IN} = 0 V, or 5 V		Room	0.6		1.5		1.5	mA
Negative Supply Current	I ₋			Room	-2.7	-5		-5		
Logic Supply Current	I _L			Room	3.1		4.5		4.5	
Reference Supply Current	I _R			Room	-1	-2		-2		

Notes:

- Refer to PROCESS OPTION FLOWCHART.
- Room = 25°C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.

**SPECIFICATIONS^a FOR DG190**

Parameter	Symbol	Test Conditions Unless Specified		Temp ^b	Typ ^c	A Suffix		B Suffix		Unit
						-55 to 125°C		-25 to 85°C		
V ₊ = 15 V, V ₋ = -15 V, V _L = 5 V V _R = 0 V, V _{IN} = 0.8 V or 2 V ^f										
Min ^d	Max ^d	Min ^d	Max ^d							
Analog Switch										
Analog Signal Range ^e	V _{ANALOG}			Full		-7.5	15	-7.5	15	V
Drain-Source On-Resistance	r _{DS(on)}	I _S = -10 mA, V _D = -7.5 V		Room Full	18		30 60		50 75	Ω
Source Off Leakage Current	I _{S(off)}	V _S = ±10 V, V _D = ∓10 V V ₊ = 10 V, V ₋ = -20 V		Room Hot	0.06		1 100		5 100	nA
		V _S = ±7.5 V, V _D = ∓7.5 V		Room Hot	0.1		1 100		5 100	
Drain Off Leakage Current	I _{D(off)}	V _S = ±10 V, V _D = ∓10 V V ₊ = 10 V, V ₋ = -20 V		Room Hot	0.05		1 100		5 100	
		V _S = ±7.5 V, V _D = ∓7.5 V		Room Hot	0.06		1 100		5 100	
Channel On Leakage Current	I _{D(on)}	V _D = V _S = ±7.5 V		Room Hot	-0.02	-2 -200		-10 -200		
Digital Input										
Input Current with Input Voltage High	I _{INH}	V _{IN} = 5 V		Room Hot	<0.01		10 20		10 20	μA
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0 V		Full	-30	-250		-250		
Dynamic Characteristics										
Turn-On Time	t _{on}	See Switching Time Test Circuit		Room	85		150		180	ns
Turn-Off Time	t _{off}			Room	95		130		150	
Source-Off Capacitance	C _{S(off)}	f = 1 MHz	V _S = -5 V, I _D = 0	Room	9					pF
Drain-Off Capacitance	C _{D(off)}		V _D = -5 V, I _S = 0	Room	6					
Channel-On Capacitance	C _{D(on)}		V _D = V _S = 0 V	Room	14					
Off Isolation	OIRR	f = 1 MHz, R _L = 75 Ω		Room	>50					dB
Power Supplies										
Positive Supply Current	I ₊	V _{IN} = 0 V, or 5 V		Room	0.6		1.5		1.5	mA
Negative Supply Current	I ₋			Room	-2.7	-5		-5		
Logic Supply Current	I _L			Room	3.1		4.5		4.5	
Reference Supply Current	I _R			Room	-1	-2		-2		

Notes:

- Refer to PROCESS OPTION FLOWCHART.
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- V_{IN} = input voltage to perform proper function.



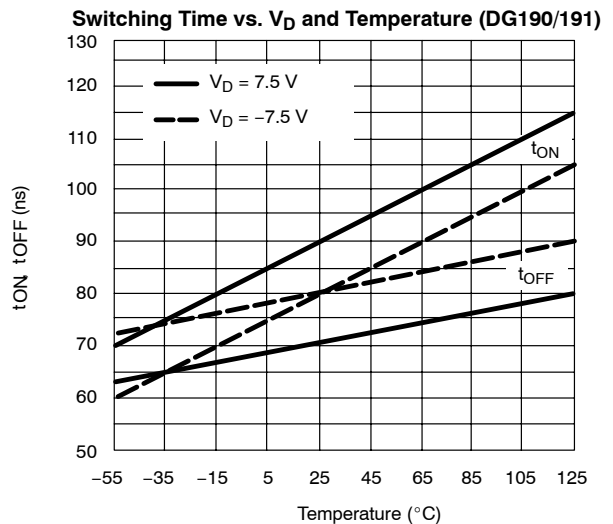
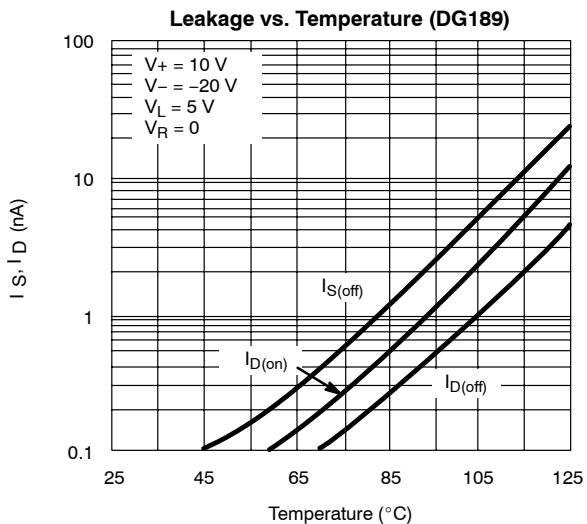
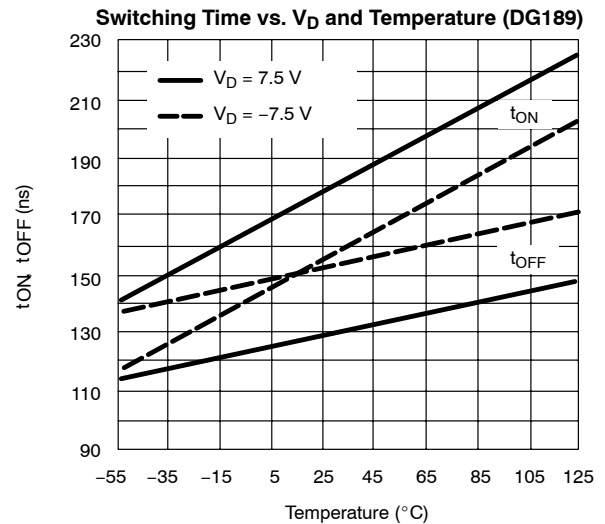
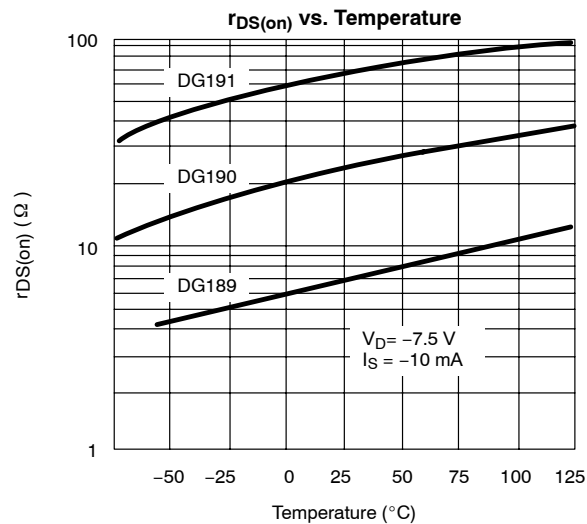
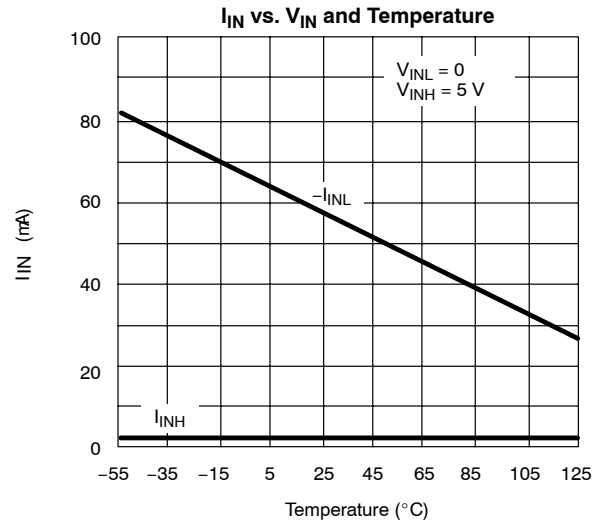
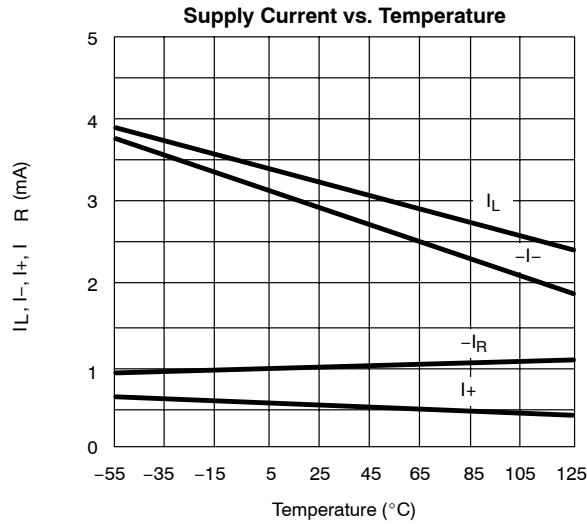
SPECIFICATIONS^a FOR DG191

Parameter	Symbol	Test Conditions Unless Specified V ₊ = 15 V, V _– = –15 V, V _L = 5 V V _R = 0 V, V _{IN} = 0.8 V or 2 V ^f	Temp ^b	Typ ^c	A Suffix –55 to 125°C		B Suffix –25 to 85°C		Unit	
					Min ^d	Max ^d	Min ^d	Max ^d		
Analog Switch										
Analog Signal Range ^e	V _{ANALOG}		Full		–10	15	–10	15	V	
Drain-Source On-Resistance	r _{DS(on)}	I _S = –10 mA, V _D = –7.5 V	Room Full	35		75 150		100 150	Ω	
Source Off Leakage Current	I _{S(off)}	V _S = ±10 V, V _D = ∓10 V V ₊ = 10 V, V _– = –20 V	Room Hot	0.05		1 100		5 100	nA	
		V _S = ±10 V, V _D = ∓10 V	Room Hot	0.07		1 100		5 100		
Drain Off Leakage Current	I _{D(off)}	V _S = ±10 V, V _D = ∓10 V V ₊ = 10 V, V _– = –20 V	Room Hot	0.04		1 100		5 100		
		V _S = ±10 V, V _D = ∓10 V	Room Hot	0.05		1 100		5 100		
Channel On Leakage Current	I _{D(on)}	V _D = V _S = ±10 V	Room Hot	–0.03	–2 –200		–10 –200			
Digital Input										
Input Current with Input Voltage High	I _{INH}	V _{IN} = 5 V	Room Hot	<0.01		10 20		10 20	μA	
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0 V	Full	–30	–250		–250			
Dynamic Characteristics										
Turn-On Time	t _{on}	See Switching Time Test Circuit		Room	120		250		300	ns
Turn-Off Time	t _{off}			Room	100		130		150	
Source-Off Capacitance	C _{S(off)}	f = 1 MHz	V _S = –5 V, I _D = 0	Room	9				pF	
Drain-Off Capacitance	C _{D(off)}		V _D = –5 V, I _S = 0	Room	6					
Channel-On Capacitance	C _{D(on)}		V _D = V _S = 0 V	Room	14					
Off Isolation	OIRR	f = 1 MHz, R _L = 75 Ω		Room	>50				dB	
Positive Supply Current	I ₊	V _{IN} = 0 V, or 5 V		Room	0.6		1.5		1.5	mA
Negative Supply Current	I _–			Room	–2.7	–5		–5		
Logic Supply Current	I _L			Room	3.1		4.5		4.5	
Reference Supply Current	I _R			Room	–1	–2		–2		

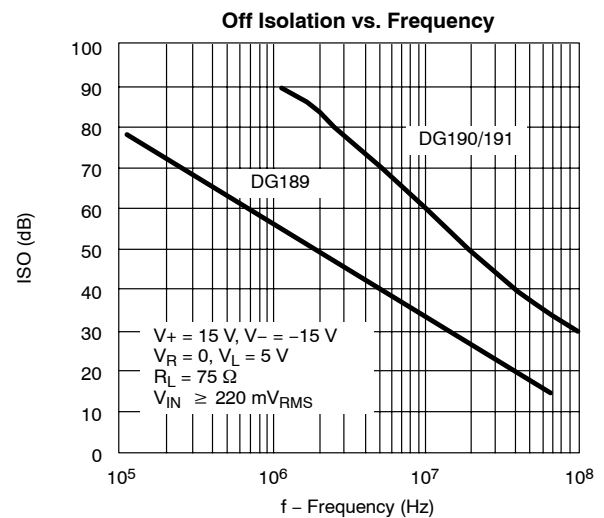
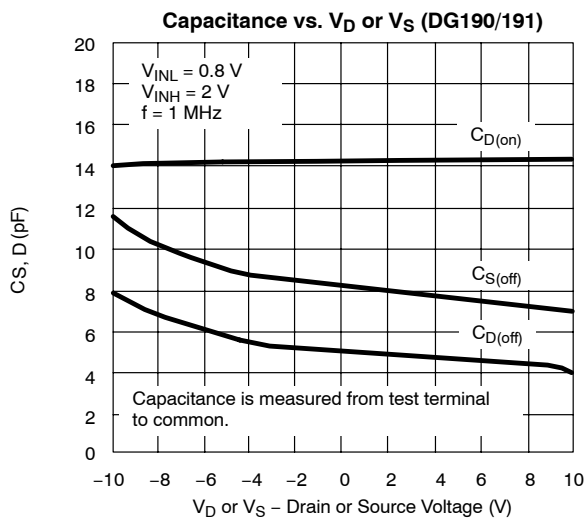
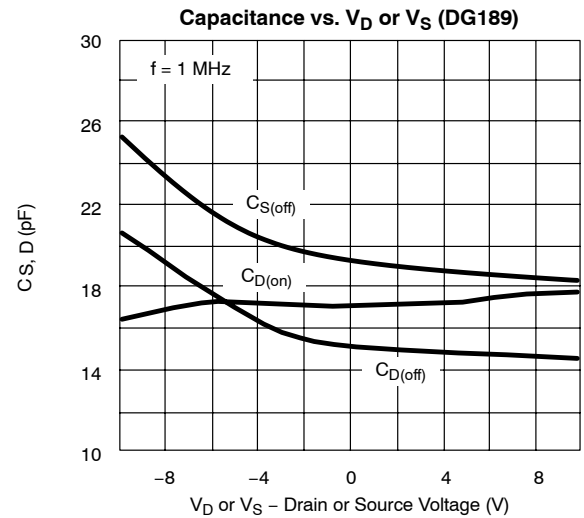
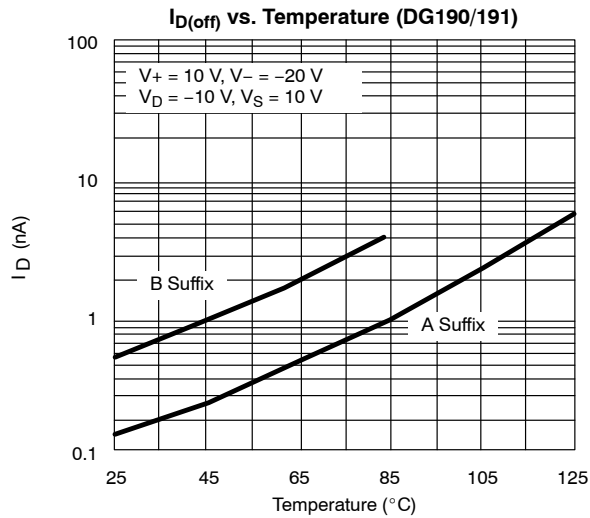
Notes:

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- V_{IN} = input voltage to perform proper function.

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)





TEST CIRCUITS

Feedthrough due to charge injection may result in spikes at the leading and trailing edge of the output waveform.

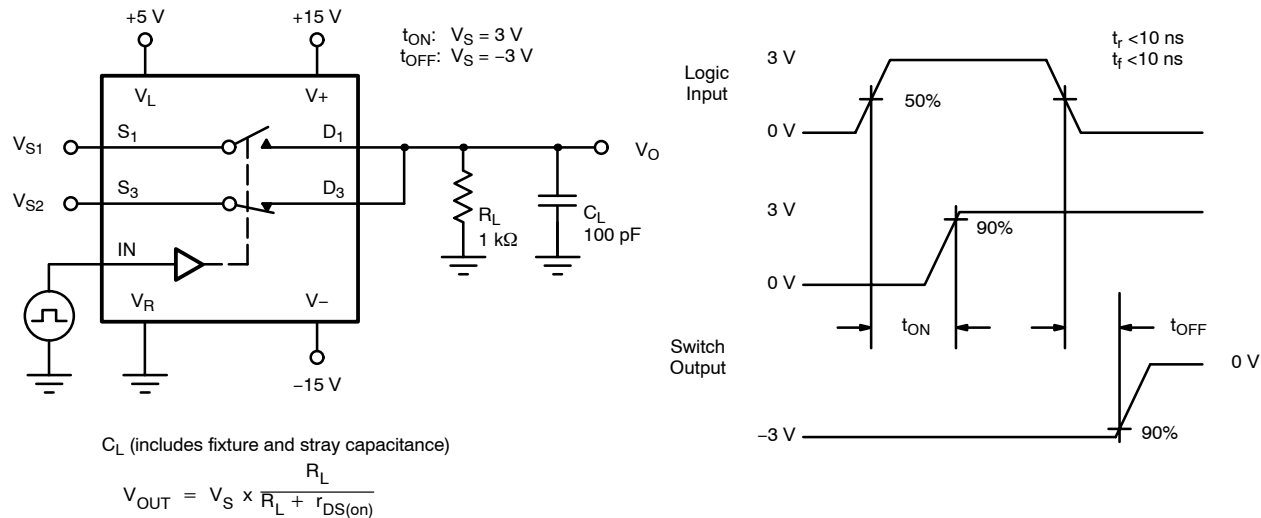


FIGURE 2. Switching Time

APPLICATION HINTS ^a						
Switch	V+ Positive Supply Voltage (V)	V- Negative Supply Voltage (V)	V _L Logic Supply Voltage (V)	V _R Reference Supply Voltage (V)	V _{IN} Logic Input Voltage V _{INH(min)} /V _{INL(max)} (V)	V _S Analog Voltage Range (V)
DG189 DG190	15 ^b	-15	5	GND	2.0/0.8	-7.5 to 15
	10	-20	5	GND	2.0/0.8	-12.5 to 10
	12	-12	5	GND	2.0/0.8	-4.5 to 12
DG191	15 ^b	-15	5	GND	2.0/0.8	-10 to 15
	10	-20	5	GND	2.0/0.8	-15 to 10
	12	-12	5	GND	2.0/0.8	-7 to 12

Notes:

a. Application Hints are for DESIGN AID ONLY, not guaranteed and not subject to production testing.

b. Electrical Parameter Chart based on V+ = 15 V, V_L = 5 V, V_R = GND



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